

# **Plasma Excitations in Graphene: Their Spectral Intensity and Temperature Dependence in Magnetic Field**

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raphene, a flat monolayer of carbon atoms with a honeycomb lattice, is the basic building block for other graphitic materials. It is famous for the linear energy dispersion around the zero Fermi energy, where the electrons can travel thousands of interatomic distances without scattering. Based on the high electron mobility. graphene is a popular candidate for the production of future nanoelectronic elements, such as ballistic transistors,<sup>1-3</sup> integrated circuit components,<sup>4,5</sup> and transparent conducting electrodes.<sup>6,7</sup> Other novel physics like an anomalous quantum Hall effect,<sup>8,9</sup> curious optical properties such as high opacity,<sup>10,11</sup> saturable absorption,<sup>12</sup> peculiar magneto-optical selection rules,13 high thermal conductivity,<sup>14,15</sup> mechanical properties,<sup>16,17</sup> and variable stacking effects<sup>18,19</sup> make it a possibly better candidate than any other known materials.

More fundamental physics and possible applications could be obtained by probing collective Coulomb excitations. Unlike bulk graphite<sup>20</sup> or bilayer graphene,<sup>21</sup> the lowfrequency plasmon is absent in undoped monolayer graphene because of the vanishing density of states at the Fermi level. However, it was found that a rise in temperature could generate free carriers and thus intraband plasmons.<sup>22</sup> Accordingly, monolayer graphene could be the first undoped system which exhibits the low-frequency plasmon purely due to temperature. For doped graphene, a finite density of states at the Fermi level would lead to collective plasmon interactions at long wavelengths.<sup>23-25</sup> The dependence of the plasmon frequency on the momentum is described as  $\omega_P \sim \sqrt{q}$ similar to that of a two-dimensional electron gas (2DEG).

The collective plasma excitations of graphene in a perpendicular external magnetic

ABSTRACT In this paper, we calculated the dielectric function, the loss function, the magnetoplasmon dispersion relation and the temperature-induced transitions for graphene in a uniform perpendicular magnetic field B. The calculations were performed using the Peierls tight-binding model to obtain the energy band structure and the random-phase approximation to determine the collective plasma excitation spectrum. The single-particle and collective excitations have been precisely identified based on the resonant peaks in the loss function. The critical wave vector at which plasmon damping takes place is clearly established. This critical wave vector depends on the magnetic field strength as well as the levels between which the transition takes place. The temperature effects were also investigated. At finite temperature, there are plasma resonances induced by the Fermi distribution function. Whether such plasmons exist is mainly determined by the field strength, temperature, and momentum. The inelastic light scattering spectroscopies could be used to verify the magnetic field and temperature induced plasmons.

KEYWORDS: graphene · Landau level · electronic excitation · random phase approximation · magnetic field · tight-binding model

field are not fully understood and still need further investigation. A uniform magnetic field can change the electron density of states and consequently enhance the absorption of the low-lying plasma excitations. Previous work based on the effective-mass model gives the qualitative behavior for magnetoplasmons in graphene.<sup>26,27</sup> However, a detailed quantitative analysis has not yet been presented. The difficulty is that the Dirac equation can only describe the electron behavior very close to the Fermi level (within the energy range of  $\pm 0.5$  eV), and the energy dispersion gradually becomes anisotropic outside this energy interval. In contrast, by utilizing the Peierls tight-binding model<sup>28</sup> and band-like matrix numerical techniques,<sup>13,29</sup> the entire  $\pi$ -magnetoelectronic structure at realistic magnetic field strengths can be solved. The number of charge carriers per area is self-conserved during our calculations. Therefore, the accuracy of our results is not constrained by either the energy range or the magnetic field. In the

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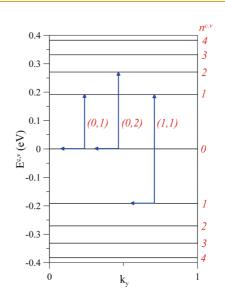
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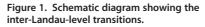


random-phase approximation (RPA), the complete structure of the dielectric function was determined. The single-particle and collective excitations can be precisely identified according to the divergences in the loss function  $Im(-1/\varepsilon(q,\omega))$ , where q is the in-plane wave vector and  $\omega$  is the frequency. It should be noted that our discussion is within the condition that q is much smaller than the reciprocal-lattice vector, and the local-field effects<sup>30,31</sup> are neglected in our calculation. The group velocities of the magnetoplasmons in the long wavelength limit are typically positive, and then decrease to negative values as the wave vector is increased. The critical momentum for plasmon damping to occur is clearly established. Our calculations show that this critical wave vector has a strong dependence on the field strength as well as the levels between which the transition takes place. The temperature effects were also investigated and are reported in detail below. We found that the intra-Landau level transitions could be induced by increasing temperature at sufficiently low magnetic fields. As a matter of fact, the peaks corresponding to these frequencies, which are below the lowest inter-Landau level transition, reduce the threshold frequency. This feature arises from the unequally spaced Landau levels (LLs) in graphene.

## **RESULTS AND DISCUSSION**

A uniform perpendicular magnetic field in monolayer graphene creates many dispersionless LLs at low energy. On the basis of the node structure of the Landau wave functions, the quantum number  $n^{c}$  ( $n^{v}$ ) for each conduction (valence) LL could be determined by counting the number of zeroes; this is the same as the number labeling the nth unoccupied (occupied) LL above (below) the Fermi energy  $E_{\rm F} = 0$ . In undoped graphene, electrons will be excited from valence LLs to conduction LLs through light absorption, for example. However, the Coulomb interaction could affect the single-particle excitation mode with energy  $\hbar \omega_{ex} =$  $E_{n^c}(k + q) - E_{n^v}(k)$  and a transferred momentum q. Each inter-Landau level excitation channel is labeled by  $(n^{v}, n^{c})$  and the transition order  $\Delta n = n^{v} - n^{c}$ , as depicted in Figure 1. For example, (0,1) denotes the transition from the highest occupied LL to the second low unoccupied LL and has the same excitation energy as (1,0) because of the inversion symmetry between the conduction and valence LLs. In collective mode excitations, the pair number denotes the channel with the largest contribution; this channel dominates the excitation at a large or small limit of q. In particular, the  $n^{c,v} = 0$  LL across the Fermi level may be half-filled in undoped graphene. The spin-up and spin-down states would be, respectively, at the conduction and valence bands if the Zeeman effects were considered. However, here we only deal with charge density fluctuations;





there is no (0,0) excitation branch since the transition must be spin-preserved.

The single-particle excitation (SPE) spectrum and the spectrum of collective plasmon modes due to the screened Coulomb interaction can be well described by the behavior of the imaginary part  $\varepsilon_2$  and the real part  $\varepsilon_1$  of the dielectric function. In the absence of a magnetic field,  $\varepsilon_2$  is divergent at  $\omega_0 = v_F q$  in the asymmetric form  $1/(\omega - \omega_0)^{1/2}$  due to the linear energy dispersion. This is shown by the red curve in Figure 2a. On the other hand, the function  $\varepsilon_1$  shown as the black curve is found to diverge as  $1/(\omega_0 - \omega)^{1/2}$ . When a magnetic field is applied, the dielectric function shows the features displayed in Figure 2 panels b-d. Each Landau level transition channel produces a symmetric peak in  $\varepsilon_2$  and a pair of asymmetric peaks along with zero points in  $\varepsilon_1$ . The zero points at which  $\varepsilon_2$  vanishes, then corresponding to these zero points, are the frequencies of the undamped plasmon resonances. The peak strength, determined by the Coulomb matrix elements  $v_a |\langle n; k + q | e^{iqy} | m; k \rangle|^2$  shown in eqs 2 and 4, strongly depends on q. At  $q = 20 (10^{5}/\text{cm})$ , the lowest excitation channel (1,0) makes the largest contribution to the low frequency dielectric function as seen in Figure 2b. Other transition channels are relatively weak. Increasing q enhances the SPEs that occur at higher frequencies, which involve the higher LLs. The frequencies at which the highest peaks occur are dependent on q. Other peaks further away from these frequencies decay quickly.

The loss function, defined as  $Im[-1/\varepsilon(q,\omega)]$ , is useful for understanding the collective excitations and the measured excitation spectra, such as inelastic light and electron scattering spectroscopies. Figure 3a shows that at **B** = 0 (green line), no prominent peak exists at low  $\omega$ , whereas an external magnetic field gives rise to some noticeable peaks. These peaks may be regarded

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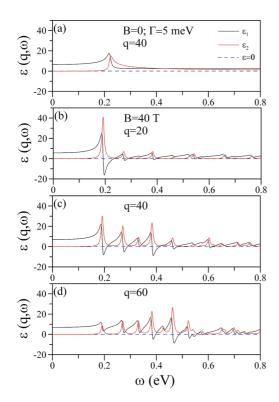


Figure 2. The real and imaginary parts of the dielectric function  $\varepsilon(q,\omega)$  as a function of frequency  $\omega$  for selected wave numbers q. (a) B = 0 and q = 40, (b) B = 40 T and q = 20, c) B = 40 T and q = 40, and (d) B = 40 T and q = 60. The wavenumber q is measured in units of 10<sup>5</sup> cm<sup>-1</sup>, here and elsewhere in this paper.

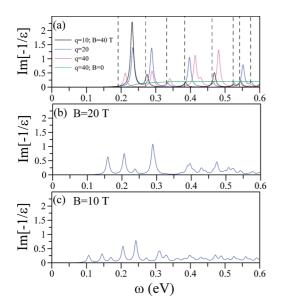


Figure 3. The loss functions at B = 40 T (a) for different values of the in-plane wave vector qq in (a), and for different field strengths in (b) and (c).

as particle—hole-like or collective plasma excitations based on the strength of the resonance, or may be ascertained by their frequency. The former modes have frequencies close to the single particle excitations (black dashed lines) subject to rather strong Landau

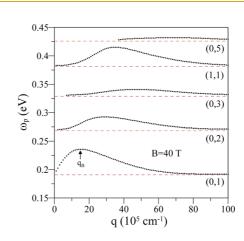


Figure 4. Plot of magnetoplasmon frequency as a function of the in-plane wave vector q. Only several of the lowest branches are shown. We choose a magnetic field of B = 40 T.

damping with a finite value for  $\varepsilon_2$ , or without a zero point in  $\varepsilon_1$ . On the other hand, the latter corresponds to a zero point in  $\varepsilon_1$  and a vanishing value in  $\varepsilon_2$  in the gap region between two SPE energies. The smaller the derivative of  $\varepsilon_1$  with respect to frequency at the plasmon frequency  $\omega_{p}$ , the higher will be the plasmon peak, as discussed in electron energy loss calculations for plasma excitations in the two-dimensional electron gas as well as nanotubes.<sup>32,33</sup> The peak distribution, including the number, position, and intensity, strongly depends on q, which demonstrates the delocalized Landau states under Coulomb interactions. At smaller q, the low lying LLs dominate the excitation spectrum, which shifts to higher LLs when q is increased. The plasmon peaks arising from the higher LL transitions have shorter heights mainly because of the reduced wave function overlap and the larger Landau damping out of the denser LL distribution. The loss function is also modulated by the field strength, as shown in Figures 3b and 3c. The threshold frequency decreases and the number of peaks increases by lowering the field strength.

The plasmon dispersion relation is shown in Figure 4. The frequencies of these collective modes correspond to peak positions of  $Im[-1/\varepsilon(q,\omega)]$  when plotted as a function of  $\omega$  for fixed q. The minimum excitation energy of each transition channel approaches the SPE energy (red dashed lines) in both the short and long wavelength limits where the polarization shift may be neglected. Plasmons may be excited over a limited range of the wave vector q. A characteristic behavior of the magnetoplasmons is that in the long wavelength limit their group velocity is positive; this group velocity then decreases as the wave vector is increased, and becomes zero at  $q_{\rm B}$  where the length scale for density fluctuations is comparable to the cyclotron radius. For  $q > q_{\rm B}$ , the group velocity of the magnetoplasmons is negative and their frequencies approach those of the SPEs. In this range of wave vectors, the magnetoplasmons encounter a loss and will be completely damped

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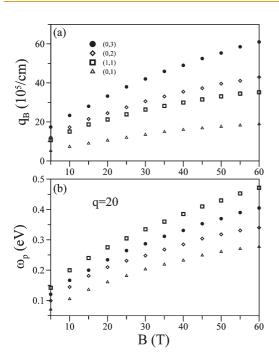


Figure 5. (a) Wave number  $q_{\rm B}$ , where the magnetoplasmon group velocity is zero, as a function of the magnetic field. (b) Magnetoplasmon frequency for q = 20 as a function of the magnetic field.

at a large limit of q. From a classical point of view, the charge density oscillations experience an external restoring force which comes from the magnetic field. The interaction between carriers and the magnetic field gradually becomes more important than the electron—electron Coulomb interaction and dominates the excitation structure as q is increased. It is noted that the plasmon dispersion broadens and the threshold momentum of the interband excitations increases with the augmentation of the transition order. This is a result of the broadening of the higher Landau wave functions.

The critical wave vector  $q_{\rm B}$ , which represents the limit momentum within which the electron wave could propagate, gradually rises with **B** as shown in Figure 5a. The higher  $q_{\rm B}$  at larger **B** corresponds to the stronger resonances in loss function (Figure 3). The dependence of the energy-loss-peak positions on the magnetic field is shown in Figure 5b. The same set of excitation frequencies simply shifts for higher magnetic fields.

Temperature could induce free electrons and holes and then the intraband e—h excitations. The distribution probability of these free carriers is described by the Fermi—Dirac function. In the absence of a magnetic field, the total carrier number per area *N* is proportional to  $T^2$ , as depicted in the inset of Figure 6b. The strong dependence demonstrates the  $\pi$ -band characteristics: zero band gap and strong wave vector-dependence. In a uniform magnetic field, *N* would begin at a finite value that is mainly attributed to the n = 0 LL. When the temperature is sufficiently high, *N* is close to that at **B** = 0 because of the reduced LL spacings at higher energy.

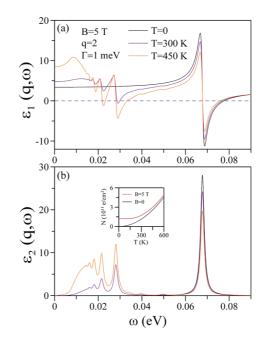


Figure 6. Plots of (a) the real part and (b) the imaginary part of the dielectric function as a function of the frequency for a chosen magnetic field and a in-plane wave vector *q*. Three different temperatures were chosen in these calculations. The inset in panel b shows the number of carriers per unit area as a function of the temperature for two chosen magnetic fields.

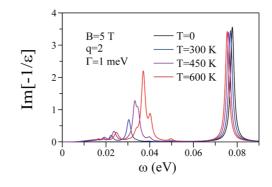


Figure 7. The loss function as a function of the frequency for a chosen magnetic field and a in-plane wave vector. Results are presented for four temperatures.

To observe the apparent temperature effects, the magnetic field must be sufficiently small. Here, we choose  $\mathbf{B} = 5 \text{ T}$  and give the illustrations of temperaturedependent dielectric functions in Figure 6 (please note that  $\Gamma$  is set smaller in order to fit the narrower LL spacings). The intra-LL and inter-LL transitions coexist at finite temperature. They are marked by sharp peaks in the loss function, as shown in Figure 7. For intra-LL transitions, the corresponding singular structures in  $\varepsilon$ become more pronounced and  $\varepsilon_1(\omega)$  approaches zero more slowly with an increase of the temperature, while the opposite is true for the inter-LL transitions. Consequently, the intra-LL plasmon undergoes a blue shift and its resonance peak is increased. In contrast, the inter-LL plasmon is red-shifted with its height slightly reduced.

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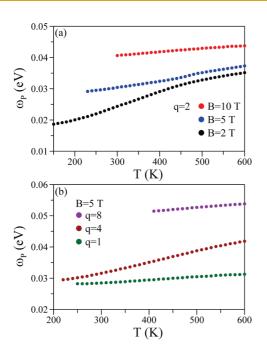


Figure 8. The temperature-dependent intra-LL plasmon frequencies at (a) different magnetic fields and (b) different momentum.

The *T*-dependent behavior of the low-frequency plasmons at different magnetic fields is shown in Figure 8a. To support the intra-LL plasmons, the temperature should be higher than  $T_c$ . For a smaller **B**, a lower  $T_c$  is needed. Moreover, in a weaker magnetic field,  $\omega_p$  shows a stronger dependence on *T*. This results from the more low-lying occupied LLs. The *T*-dependent behavior is also dominated by the wave vector, as shown in Figure 8b.  $T_c$  could achieve the minimum at a critical value of *q* and then increase; the opposite is true for the degree of  $\omega_p$ –*T* dependence. This behavior may be traced to the peculiar  $\omega_p$ –*q* relation.

## SUMMARY AND CONCLUSIONS

We have employed the Peierls tight-binding Hamiltonian to calculate the electron energy bands for graphene in a uniform perpendicular magnetic field. The eigenvalues and eigenvectors were obtained efficiently by properly rearranging the base functions. With the obtained results, we were able to calculate the longitudinal wave vector and frequency-dependent dielectric function at an arbitrary temperature. The entire LL spectrum was included in our calculations. This ensures the correctness of the dielectric function in the RPA and consequently the plasmon intensity and its frequency. We presented the magnetoplasmon excitation spectra at magnetic fields which may be achieved experimentally. The exact diagonalization method could also be applicable to multilayer graphene or bulk graphite over a wide range of electric and magnetic fields.

The peaks in the loss function may be classified as a collective mode or single-particle-like excitation. The former corresponds to a zero point in  $\varepsilon_1$  at which  $\varepsilon_2$ is very small, while the latter relates to a finite value of  $\varepsilon_2$ . The peak is a function of in-plane wave vector q and the magnetic field **B**. The critical momentum, through which the magnetoplasmon dispersion passes and enters into the single particle mode excitation region, is clearly identified. It depends on the transition channel and the magnetic field. The temperature effects become important when the magnetic field is sufficiently small. Extra plasmon peaks that arise from intra-LL transitions could occur in the infrared regime. The critical temperature for inducing the low-frequency modes is determined by **B** and *q*. The numerical results may be validated by inelastic lightscattering which has been successfully applied to the two-dimensional electron gas system in magnetic fields.34,35

#### **METHODS**

Monolayer graphene consists of two sublattices of A and B atoms with a C–C bond length of b = 1.42 Å. The hopping integral between two nearest-neighbor atoms is  $\gamma_0 = 2.598$  eV. In the tight-binding model, it is convenient to present the crystal Hamiltonian in terms of the Bloch functions of the two periodic carbon atom wave functions  $|A\rangle$ ,  $|B\rangle$ . Here, we only take the  $2p_z$ orbitals to investigate the low-energy electronic structure. The monolayer graphene is assumed to be in an ambient uniform magnetic field  $\mathbf{B} = B\hat{z}$ . The magnetic flux, the product of the field strength and the hexagonal area, is  $\Phi = [3\sqrt{3b^2B/2}]/\phi_0$  where the flux quantum  $\phi_0 = hc/e = 4.13561015 \text{ T/m}^2$ . The vector potential, which is chosen as  $\mathbf{A} = Bx\hat{y}$ , leads to a new periodicity along the armchair direction. The Hamiltonian matrix element can be obtained through multiplication of the Hamiltonian matrix element in zero field by a Peierls phase.<sup>28</sup> Such phase has the period  $R_B = 1/\Phi$ . This performance assumes that the magnetic field changes slowly as a function of the lattice constant.<sup>36</sup> Therefore, the enlarged unit cell contains 4R<sub>B</sub> carbon atoms and the Hamiltonian matrix is  $4R_B \times 4R_B$ . The

nearest-neighbor hopping integral associated with the extra position-dependent Peierls phase is given by

$$\langle B_{k}|H|A_{j}\rangle = \gamma_{0} \exp[i\mathbf{k} \cdot (\mathbf{R}_{A_{j}} - \mathbf{R}_{B_{k}})]$$

$$\times \exp\left\{i\left[\frac{2\pi}{\phi_{0}}\int_{\mathbf{R}_{A_{j}}}^{\mathbf{R}_{B_{k}}}\mathbf{A} \,\mathrm{dr}\right]\right\}$$

$$= \gamma_{0}t_{j}\delta_{i,k} + \gamma_{0}s\delta_{i,k+1} \qquad (1)$$

where  $t_j = \exp\{i[-k_x^{b}/_2 - k_y(\sqrt{3}b)/2 + \pi\Phi(j - 1 + \frac{1}{6})]\} + \exp\{i[-k_x^{b}/_2 + k(\sqrt{3}b)/2 - \pi\Phi(j - 1 + \frac{1}{6})], s = \exp[i(-k_x)b]],$ and  $\mathbf{k} = (k_x,k_y)$  is the Bloch electron wave vector. The complete Hamiltonian matrix expression can be seen in ref 37. By diagonalizing the Hamiltonian, the eigenenergy  $E^{c,v}$  and the wave function  $\Psi^{c,v}$  are derived (c and v refer to the conduction and valence bands, respectively). In the regular matrix, the eigenstates can only be obtained for about an 800 × 800 matrix (for  $\mathbf{B} = 400$  T). To satisfy realistic conditions under which experiments are conducted ( $\mathbf{B} < 50$  T for a 6400 × 6400 matrix),

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we build a band-like matrix by rearranging the base Bloch functions.<sup>13,29,37</sup> This enables us to diagonalize the large matrix and find a solution for the Landau wave functions.

Electronic excitations are characterized by the transferred momentum q and the excitation frequency  $\omega$ , which determine the dielectric function. The dynamical dielectric function, calculated using the self-consistent-field approach, is

$$\varepsilon(q,\omega) = \varepsilon_0 - v_q \chi(q,\omega) \tag{2}$$

where  $v_q = 2\pi e^2/q$  is the in-plane Fourier transformation of the bare Coulomb potential energy and  $\varepsilon_0 = 2.4$  is the background dielectric constant for graphene. The linear response function is given by<sup>38,39</sup>

$$\chi(q,\omega) = 2 \sum_{h,h'=c,v} \sqrt{\int_{1stBZ} \frac{dk_x dk_y}{(2\pi)^2}} |\langle h'; \mathbf{k} + \mathbf{q} | e^{i\mathbf{q}\mathbf{r}} | h; \mathbf{k} \rangle|^2$$
$$\times \frac{f(E^{h'}(\mathbf{k} + \mathbf{q})) - f(E^h(\mathbf{k}))}{E^{h'}(\mathbf{k} + \mathbf{q}) - E^h(\mathbf{k}) - (\omega + i\Gamma)}$$
(3)

The Fermi–Dirac distribution is  $f(E) = 1/[1 + \exp(E - \mu/k_{\rm B}T)]$ , where  $k_{\rm B}$  is the Boltzmann constant and  $\Gamma$  is the energy broadening which results from various deexcitation mechanisms. Furthermore,  $\mu$  is the chemical potential which is maintained at zero for any *T* due to the symmetry of the energy band structure about the Fermi level. The factor of 2 accounts for the spin degeneracy. Our discussion is constrained at the condition that *q* is largely smaller than the reciprocal lattice vector, and thus local-field effects can be ignored.<sup>31</sup> In the presence of the magnetic field, the system becomes fully quantized. The summation in eq 3 becomes a sum over all possible single particle transitions between Landau states  $|m\rangle$  and  $|n\rangle$ . The response function is now rewritten as

$$\chi(q,\omega) = \frac{1}{3bR_B\pi} \sum_{n,m;k} |\langle n; k+q| e^{iqy} |m; k \rangle|^2_{q=q_y;k=k_y}$$
$$\times \frac{f(E_n) - f(E_m)}{E_n - E_m - (\omega + i\Gamma)}$$
(4)

Only  $q_y$  and  $k_y$  components are considered here. The calculation along the other direction of  $q_x$  and  $k_x$  obtains the same results. This isotropic characteristic of Landau system is the same with that in Quinn's paper.<sup>40</sup> Since all the  $\pi$ -electronic states are included in the calculations, the strength and frequency of the resonances in  $Im(-1/\epsilon)$  can be correctly defined. Moreover, calculations on temperature effects and highly doped systems (currently in work) are allowed.

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